# NEC

# PNP SILICON POWER TRANSISTOR **2SB1151**

**DESCRIPTION** 

The 2SB1151 is a Low  $V_{\text{CE(sat)}}$  transistor which has a large current capability and wide SOA.

It is suitable for DC-DC converter, or driver of solenoid or motor.

**FEATURES** 

Low Collector Saturation Voltage.

 $V_{CE(sat)} = -0.14 \text{ V TYP.}$  (@  $I_C/I_B = -2.0 \text{ A}/-0.2 \text{ A}$ )

• Large Current.

 $I_{C(DC)} = -5.0 \text{ A}, I_{C(pulse)} = -8.0 \text{ A}$ 

- High Total Power Dissipation. : P<sub>T</sub> = 1.3 W
- Complementary to 2SD1691.

#### ABSOLUTE MAXIMUM RATINGS

Maximum Temperatures

 $V_{CBO}$ 

Maximum Power Dissipations

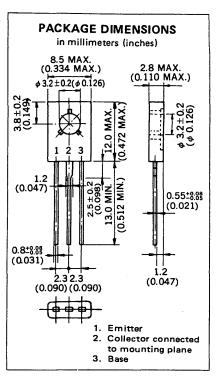
Total Power Dissipation ( $T_a = 25 \,^{\circ}\text{C}$ ) . . . . . . . 1.3 W Total Power Dissipation ( $T_c = 25 \,^{\circ}\text{C}$ ) . . . . . . 20 W

Collector to Base Voltage . . . . . . . . .

Maximum Voltages and Currents (T<sub>a</sub> = 25 °C)

$V_{CEO}$	Collector to Emitter Voltage	-60	٧
$V_{EBO}$	Emitter to Base Voltage	<b>-7.0</b>	٧
I <sub>C(DC)</sub>	Collector Current	-5.0	Α
I <sub>C(pulse)</sub> *	Collector Current	-8.0	Α
I <sub>B(DC)</sub>	Base Current	-1.0	Α

<sup>\*</sup> PW  $\leq$  10 ms, Duty Cycle  $\leq$  50 %



### ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
VCE(sat)**	Collector Saturation Voltage		-0.14	-0.3		I <sub>C</sub> = -2.0 A, I <sub>B</sub> = -0.2 A
V <sub>BE(sat)</sub> **	Base Saturation Voltage		-0.9	-1.2	V	$I_C = -2.0 \text{ A}, I_B = -0.2 \text{ A}$
hFE1 **	DC Current Gain	60			-	$V_{CE} = -1.0 \text{ V}, I_{C} = -0.1 \text{ A}$
hFE2**	DC Current Gain	100	200	400	-	$V_{CE} = -1.0 \text{ V, } I_{C} = -2.0 \text{ A}$
hFE3**	DC Current Gain	50			-	$V_{CE} = -2.0 \text{ V, I}_{C} = -5.0 \text{ A}$
СВО	Collector Cutoff Current			-10	μΑ	$V_{CB} = -50 \text{ V, } I_E = 0$
IEBO	Emitter Cutoff Current			-10	μΑ	$V_{EB} = -7.0 \text{ V, I}_{C} = 0$
ton	Turn On Time		0.15	1.0	μs	
t <sub>stg</sub>	Storage Time		0.78	2.5	μs	$(I_C = -2.0 \text{ A}, I_{B1} = -I_{B2} = 0.2 \text{ A})$ $(R_L = 5.0 \Omega, V_{CC} = -10 \text{ V})$
t <sub>f</sub>	Fall Time		0.18	1.0	μs	/ UF - 2.0 25' ACC = -10 A

<sup>\*\*</sup> PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2 %

#### Classification of hFE2

Rank	M	L	К
Range	100 to 200	160 to 320	200 to 400

Test Conditions:  $V_{CE} = -1.0 \text{ V}$ ,  $I_{C} = -2.0 \text{ A}$ 

## TYPICAL CHARACTERISTICS (Ta = 25 °C)

